Module title			Abbreviation
Semiconductor Physics and Devices			11-SPD-102-m01
Module coordinator		**Module offered by**	
Managing Director of the Institute of Applied Physics		Faculty of Physics and Astronomy	
ECTS	**Method of grading**	**Only after succ. compl. of module(s)**	
6	numerical grade	--	
Duration	**Module level**	**Other prerequisites**	
1 semester	graduate	Certain prerequisites must be met to qualify for admission to assessment. The lecturer will inform students about the respective details at the beginning of the course. Registration for the course will be considered a declaration of will to seek admission to assessment. If students have obtained the qualification for admission to assessment over the course of the semester, the lecturer will put their registration for assessment into effect. Students who meet all prerequisites will be admitted to assessment in the current or in the subsequent semester. For assessment at a later date, students will have to obtain the qualification for admission to assessment anew.	

Contents

Principles of Semiconductor Physics. Introduction to key theories on semiconductors. Components from the areas of electronics and photonics.

Intended learning outcomes

The students are familiar with the properties of semiconductors, they have gained an overview of the electronic and phononic band structures of important semiconductors and the resulting electronic, optical and thermal properties. They know the principles of charge transport and are able to apply Poisson, Boltzmann and continuity equations to the solution of questions. They have gained insights into the methods of semiconductor production and are familiar with the methods of planar technology and current developments in this sector, they have a basic understanding of component production. They understand the structure and function of the main components of electronics (diodes, transistor, FET, thyristor, diac, triac), microwave applications (tunnel, impatt, baritt and Gunn diode) and optoelectronics (photo diode, solar cell, light-emitting diode, semiconductor injection laser). They know the realisation possibilities of low-dimensional charge carrier systems on the basis of semiconductors and their technological importance. They are familiar with current developments in the field of components.

Courses (type, number of weekly contact hours, language — if other than German)

V + R (no information on SWS (weekly contact hours) and course language available)

Method of assessment (type, scope, language — if other than German, examination offered — if not every semester, information on whether module is creditable for bonus)

written examination (approx. 90 minutes) or oral examination of one candidate each or oral examination in groups (approx. 30 minutes per candidate, for modules with less than 4 ECTS credits approx. 20 minutes) or project report (approx. 8 to 10 pages, time to complete: 1 to 4 weeks) or presentation/seminar presentation (approx. 30 minutes)
Assessment offered: When and how often assessment will be offered depends on the method of assessment and will be announced in due form under observance of Section 32 Subsection 3 ASPO (general academic and examination regulations) 2009.
Language of assessment: German, English

Allocation of places

--

Additional information

--

Referred to in LPO I (examination regulations for teaching-degree programmes)

--

Module appears in

Bachelor' degree (1 major) Physics (2010)
Bachelor' degree (1 major) Physics (2012)
Bachelor' degree (1 major) Nanostructure Technology (2010)
Bachelor' degree (1 major) Nanostructure Technology (2012)
Master's degree (1 major) Mathematics (2012)
Master's degree (1 major) Physics (2011)
Master's degree (1 major) Nanostructure Technology (2011)
Master's degree (1 major) FOKUS Physics (2011)
Master's degree (1 major) Computational Mathematics (2012)
Master's degree (1 major) Functional Materials (2012)